2SA1706

ON Semiconductor®

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Bipolar Transistor -50V, -2A, Low VCE(sat), PNP Single NMP

Applicaitons

· Voltage regulators, relay drivers, lamp drivers

Features

- · Adoption of FBET, MBIT processes
- · Large current capacity and wide ASO
- · Fast switching speed

Specifications

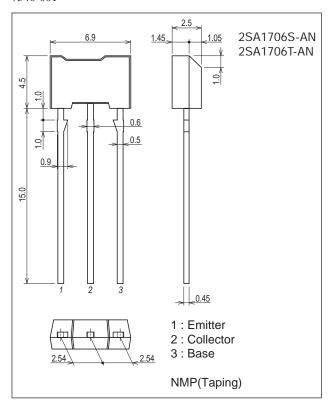
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-60	V
Collector-to-Emitter Voltage	VCEO		-50	V
Emitter-to-Base Voltage	V _{EBO}		-6	V
Collector Current	IC		-2	Α
Collector Current (Pulse)	ICP		-4	Α
Collector Dissipation	PC		1	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7540-001

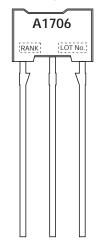


Product & Package Information

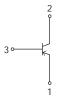
Package : NMP(Taping)JEITA, JEDEC : SC-71

• Minimum Packing Quantity: 2,500 pcs./box

Marking(NMP(Taping))



Electrical Connection



Semiconductor Components Industries, LLC, 2013

September, 2013

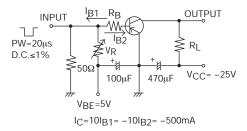
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Syllibol	Conditions	min	typ	max	Uill	
Collector Cutoff Current	ICBO	V _{CB} =-50V, I _E =0A			-100	nA	
Emitter Cutoff Current	IEBO	V _{EB} =-4V, I _C =0A			-100	nA	
DC Current Gain	h _{FE} 1	V _{CE} =-2V, I _C =-100mA	140*		400*		
DC Current Gain	h _{FE} 2	V _{CE} =-2V, I _C =-1.5A	40				
Gain-Bandwidth Product	fŢ	V _{CE} =-10V, I _C =-50mA		150		MHz	
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =-1A, I _B =-50mA		-0.3	-0.7	V	
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =-1A, I _B =-50mA		-0.9	-1.2	V	
Output Capacitance	Cob	V _{CB} =-10V, f=1MHz		22		pF	
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=-10μA, IE=0A	-60			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=-1mA, RBE=∞	-50			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =-10μA, I _C =0A	-6			V	
Turn-ON Time	ton			60		ns	
Storage Time	t _{stg}	See specified Test Circuit.		450		ns	
Fall Time	tf			30		ns	

* : The 2SA1706 is classified by 100mA hFE as follows :

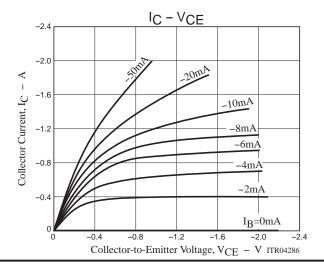
Rank	S	T	
hFE	140 to 280	200 to 400	

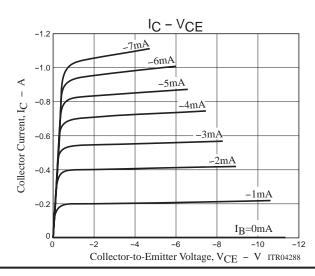
Switching Time Test Circuit

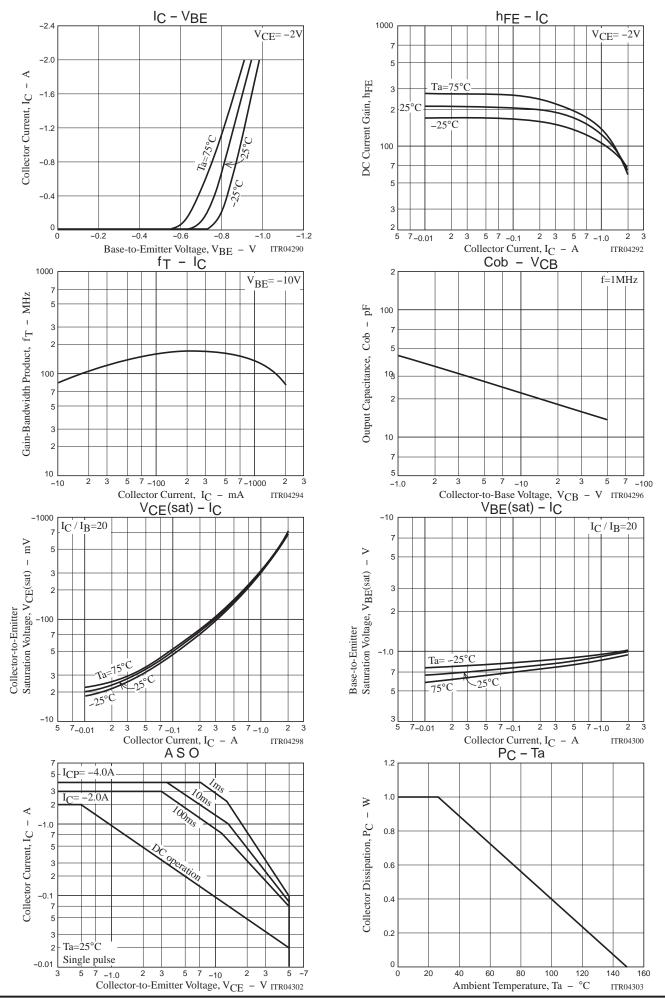


Ordering Information

	Device	Package	Shipping	memo
2SA1706S-AN		NMP(Taping)	2,500pcs./box	Pb Free
	2SA1706T-AN	NMP(Taping)	2,500pcs./box	Pb Flee







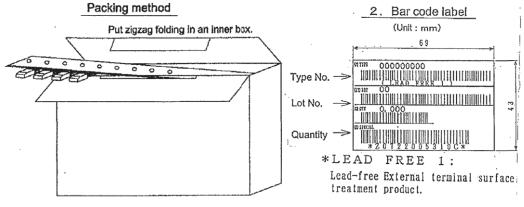
Bag Packing Specification

2SA1706S-AN, 2SA1706T-AN

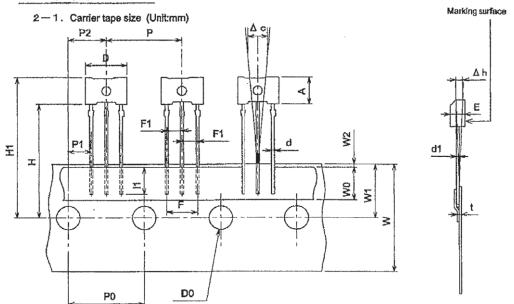
NMP (Zigzag folding)

Storage package	Package	Maximum Number of devices contained (pcs.)		Packing format		
Outline name	type	Inner box No.	Storage quantity	Outer box (C-6)	Outer box (C-8)	
NMP	AN/AZ	C-3 Inner box Dimensions :mm(external) 330×45×125		8 inner boxes contained(20,000 pcs.) Outer box Dimensions:mm(external) 5 8 5 × 3 4 5 × 1 9 5		

1. Packing format



2. Taping specifications

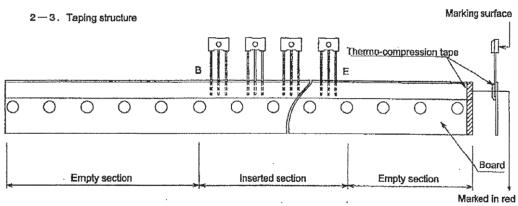


2-2. Taping size standard

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Item	Symbol	Standard	Tolerance		
	D	6.9	±0.2		
Work plece outside diameter	E	2.5	±0.2		
Work piece height	Α	4.5	±0.2		
Lead wire diameter	đ	0.5	±0.1		
Lead wire thickness	d1	0.45	±0.1		
Bonded lead wire	11	3.0MIN			
Pitch between products	Р	12.7	±0.5		
Pitch between perforations	P0	12.7	±0.2		
Total pitch for 21 perforations	P0×20	254.0	±1.0		
Distance between lead wire	F	5,0	+0.8		
Lead wire pitch distance	F1	2.54	+0.4 -0.1		
	P1	3.81	±0.3		
Displacement of perforations	P2	6.35	±0.3		
Displacement of tape	W2	0~0. 5			

Unit:mm

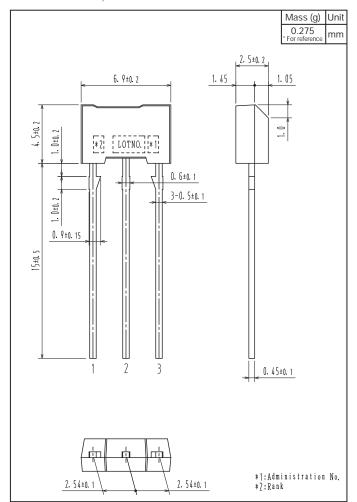
ltem	Symbol	Standard	Tolerance		
Tape width	W	18.0	土0.5		
Adhesive tape	W0	6.0	±0.5		
Displacement of perforations	W1	9.0	±0.5		
Work piece bottom surface position	Н	19.0	+1.0 -0.5		
Work piece upper limit position	H1	23.5	±1.0		
Perforations diameter	D0	φ4.0	±0.2		
Tape thickness (total thickness)	t	0.6	±0.2		
Product inclination	Δс	0	±0.7		
Product inclination	Δh	0	±1.0		



- · Provide an empty section for about three to five pieces in leading and end portions of the tape.
- · Provide an empty section in the fold-back portion.
- Provide marking in red to the E-side end of the board.

Outline Drawing

2SA1706S-AN, 2SA1706T-AN



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NTE101 NTE13 NTE15